



Product data sheet

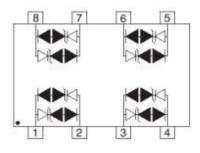
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SOP-8



Features

- 400 W Peak Pulse Power per Line (tp=8/20µs)
- Protects four line pairs
- Low capacitance
- Low Leakage Current.
- Low Operating and Clamping Voltages.
- Transient Protection for High Speed Data Lines to IEC61000-4-2(ESD)±15kV(air),±8kV(Contact) IEC61000-4-4(EFT) 40A(5/50ns)
 IEC61000-4-5(lightning) 24A(8/20us)

Applications

- Ethernet 10/100/1000 Base T
- WAN/LAN Equipment
- Desktops,Servers,Notebooks & Handhelds,base stations Laser Diode Protection

Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Peak Pulse Power (t _p = 8/20μs) - See Fig1.	Ррк	400	W
Peak Pulse Current (t _p = 8/20µs)		24	А
Storage Temperature Range		-55 to 150	°C
Operating Junction Temperature Range		-55 to 150	°C

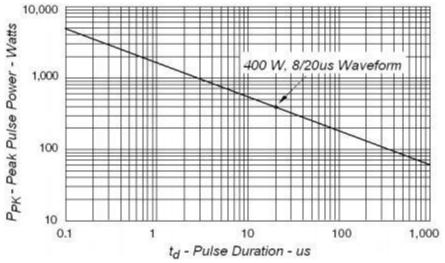


Fig1. Peak Pulse Power VS Pulse Time



SLVU2.8-8-MS HF 🐼

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Electrical Parameter

Symbol	Parameter		
I _{PP}	Peak Pulse Current		
Vc	Clamping Voltage @ I _{PP}		
V _{RWM}	Reverse Stand-Off Voltage		
I _R	Reverse Leakage Current @ V _{RWM}		
V _{SB}	Snap-Back Voltage @ I _{SB}		
I _{SB}	Snap-Back Current		
V _{PT}	Punch-Through Voltage		
I _{PT}	Punch-Through Current		

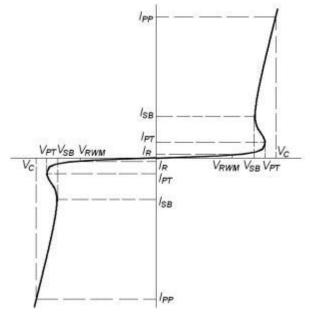
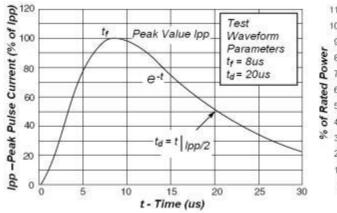


Fig2. SLVU2.8-8 IV Characteristic Curve

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V _{RWM}				2.8	V
Punch-Through Voltage	V _{PT}	I _{PT} = 2uA	3.0			V
Snap-Back Voltage	V _{SB}	I _{SB} = 50mA	2.8			V
Reverse Leakage Current	I_	V _{RWM} =2.8V, T=25℃			1	uA
	I _R	(Each Line)				
Clamping Voltage	Vc	I _{PP} =2A, t _P =8/20us			5.5	V
		(Each Line)				
Clamping Voltage	Vc	I _{PP} =5A, t _P =8/20us			8.5	V
	vc	(Each Line)		0.5	v	
Clamping Voltage	V	I _{PP} =24A, t _P =8/20us			15	V
	Vc	(Each Line)			10	
Junction Capacitance	Cj	VR =0V, f =1MHz (Each Line)		7	10	pF

Electrical Characteristics

Typical Characteristics





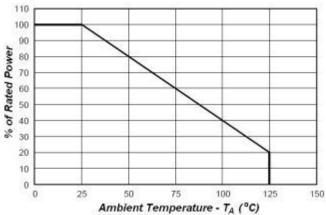
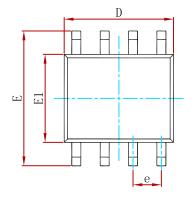
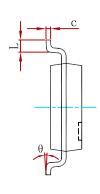


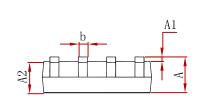
Fig4. Power Derating Curve



PACKAGE MECHANICAL DATA

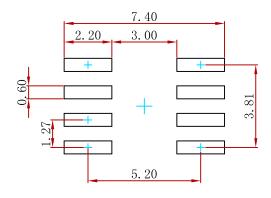






Symbol	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min	Max	Min	Max
Α	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
с	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270 (BSC)		0.050 (BSC)	
Е	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0 °	8°	0 °	8°

Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
SLVU2.8-8-MS	SOP-8	2500



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